

Figure 1: Internal schematic diagram

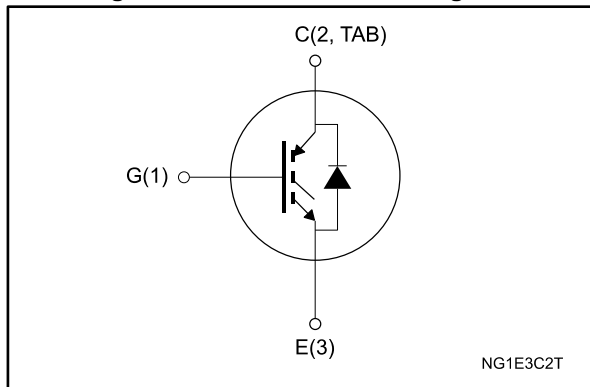


Table 1: Device summary

| Order code | Marking | Package | Packing |
|----------------|------------|--------------------|---------------|
| STGB10NC60KDT4 | GB10NC60KD | D ² PAK | Tape and reel |
| STGD10NC60KDT4 | GD10NC60KD | DPAK | |
| STGF10NC60KD | GF10NC60KD | TO-220FP | Tube |
| STGP10NC60KD | GP10NC60KD | TO-220 | |

Features

- Lower on voltage drop ($V_{CE(sat)}$)
- Lower C_{RES} / C_{IES} ratio (no cross-conduction susceptibility)
- Very soft ultra fast recovery antiparallel diode
- Short-circuit withstand time 10 μ s

Applications

- High frequency motor controls
- SMPS and PFC in both hard switch and resonant topologies
- Motor drives

Description

These devices are very fast IGBTs developed using advanced PowerMESH™ technology. This process guarantees an excellent trade-off between switching performance and low on-state behavior. These devices are well-suited for resonant or soft-switching applications.

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1 Electrical ratings

Table 2: Absolute maximum ratings

| Symbol | Parameter | Value | | | Unit |
|--------------------------------|--|-------------------------------|------|----------|------|
| | | D ² PAK, TO-220 | DPAK | TO-220FP | |
| V _{CES} | Collector-emitter voltage (V _{GE} = 0 V) | 600 | | | V |
| I _C ⁽¹⁾ | Continuous collector current at T _C = 25 °C | 20 | | 9 | A |
| | Continuous collector current at T _C = 100 °C | 10 | | 6 | A |
| I _{CL} ⁽²⁾ | Turn-off latching current | 30 | | | A |
| I _{CP} ⁽³⁾ | Pulsed collector current | 30 | | | A |
| V _{GE} | Gate-emitter voltage | ±20 | | | V |
| I _F | Diode RMS forward current at T _C =25°C | 10 | | | A |
| I _{FSM} | Surge non repetitive forward current t _p = 10 ms sinusoidal | 20 | | | A |
| P _{TOT} | Total dissipation at T _C = 25 °C | 65 | 62 | 25 | W |
| V _{ISO} | Insulation withstand voltage (RMS) from all three leads to external heat sink (t=1 s; T _C =25 °C) | 2500 | | | V |
| t _{scw} | Short-circuit withstand time V _{CE} = 0.5 V _{CES} , T _J = 125 °C, R _G = 10 Ω, V _{GE} = 12 V | 10 | | | µs |
| T _{stg} | Storage temperature range | - 55 to 150 | | | °C |
| T _J | Operating junction temperature range | | | | |

Notes:

(1) Calculated according to the iterative formula:

$$I_C(T_C) = \frac{T_{j(max)} - T_C}{R_{thj-c} \times V_{CE(sat)(max)}(T_{j(max)}, I_C(T_C))}$$

(2) V_{clamp} = 80 % V_{CES}, V_{GE} = 15 V, R_G = 10 Ω, T_J = 150 °C.

(3) Pulse width limited by maximum junction temperature and turn-off within RBSOA.

Table 3: Thermal data

| Symbol | Parameter | Value | | | Unit |
|-----------------------|--|----------------------------|------|----------|------|
| | | TO-220, D ² PAK | DPAK | TO-220FP | |
| R _{thj-case} | Thermal resistance junction-case IGBT | 1.9 | 2 | 5 | °C/W |
| R _{thj-case} | Thermal resistance junction-case diode | 4 | 4.5 | 7 | |
| R _{thj-amb} | Thermal resistance junction-ambient | 62.5 | 100 | 62.5 | |

2 Electrical characteristics

$T_C = 25\text{ °C}$ unless otherwise specified

Table 4: Static characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------|--------------------------------------|---|------|------|-----------|---------------|
| $V_{(BR)CES}$ | Collector-emitter breakdown voltage | $I_C = 1\text{ mA}$, $V_{GE} = 0\text{ V}$ | 600 | | | V |
| $V_{CE(sat)}$ | Collector-emitter saturation voltage | $V_{GE} = 15\text{ V}$, $I_C = 5\text{ A}$ | | 2.2 | 2.5 | V |
| | | $V_{GE} = 15\text{ V}$, $I_C = 5\text{ A}$, $T_j = 125\text{ °C}$ | | 1.8 | | |
| $V_{GE(th)}$ | Gate threshold voltage | $V_{CE} = V_{GE}$, $I_C = 250\text{ }\mu\text{A}$ | 4.5 | | 6.5 | V |
| I_{CES} | Collector cut-off current | $V_{CE} = 600\text{ V}$, $V_{GE} = 0\text{ V}$ | | | 150 | μA |
| | | $V_{CE} = 600\text{ V}$, $V_{GE} = 0\text{ V}$, $T_j = 125\text{ °C}$ ⁽¹⁾ | | | 1 | mA |
| I_{GES} | Gate-emitter leakage current | $V_{GE} = \pm 20\text{ V}$ | | | ± 100 | nA |
| $g_{fs}^{(2)}$ | Forward transconductance | $V_{CE} = 15\text{ V}$, $I_C = 5\text{ A}$ | | 15 | | S |

Notes:

⁽¹⁾Defined by design, not subject to production test.

⁽²⁾Pulse test: pulse duration < 300 μs , duty cycle < 2 %.

Table 5: Dynamic characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|------------------------------|--|------|------|------|------|
| C_{ies} | Input capacitance | $V_{CE} = 25\text{ V}$, $f = 1\text{ MHz}$, $V_{GE} = 0\text{ V}$ | - | 380 | - | pF |
| C_{oes} | Output capacitance | | - | 46 | - | |
| C_{res} | Reverse transfer capacitance | | - | 8.5 | - | |
| Q_g | Total gate charge | $V_{CE} = 390\text{ V}$, $I_C = 5\text{ A}$, $V_{GE} = 0\text{ to }15\text{ V}$ (see Figure 19: "Gate charge test circuit") | - | 19 | - | nC |
| Q_{ge} | Gate-emitter charge | | - | 5 | - | |
| Q_{gc} | Gate-collector charge | | - | 9 | - | |

Table 6: Switching on/off (inductive load)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------|-----------------------|--|------|------|------|------------|
| $t_{d(on)}$ | Turn-on delay time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\ \Omega$, $V_{GE} = 15\text{ V}$ (see Figure 18 : "Test circuit for inductive load switching" and Figure 20 : "Switching waveform") | - | 17 | - | ns |
| t_r | Current rise time | | - | 6 | - | ns |
| $(di/dt)_{on}$ | Turn-on current slope | | - | 655 | - | A/ μ s |
| $t_{d(on)}$ | Turn-on delay time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\ \Omega$, $V_{GE} = 15\text{ V}$, $T_j = 125^\circ\text{C}$ (see Figure 18 : "Test circuit for inductive load switching" and Figure 20 : "Switching waveform") | - | 16.5 | - | ns |
| t_r | Current rise time | | - | 6.5 | - | ns |
| $(di/dt)_{on}$ | Turn-on current slope | | - | 575 | - | A/ μ s |
| $t_{r(voff)}$ | Off voltage rise time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\ \Omega$, $V_{GE} = 15\text{ V}$ (see Figure 18 : "Test circuit for inductive load switching" and Figure 20 : "Switching waveform") | - | 33 | - | ns |
| $t_{d(off)}$ | Turn-off delay time | | - | 72 | - | ns |
| t_f | Current fall time | | - | 82 | - | ns |
| $t_{r(voff)}$ | Off voltage rise time | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\ \Omega$, $V_{GE} = 15\text{ V}$, $T_j = 125^\circ\text{C}$ (see Figure 18 : "Test circuit for inductive load switching" and Figure 20 : "Switching waveform") | - | 60 | - | ns |
| $t_{d(off)}$ | Turn-off delay time | | - | 106 | - | ns |
| t_f | Current fall time | | - | 136 | - | ns |

Table 7: Switching energy (inductive load)

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|--------------|---------------------------|---|------|------|------|---------|
| $E_{on(1)}$ | Turn-on switching energy | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\ \Omega$, $V_{GE} = 15\text{ V}$ (see Figure 18 : "Test circuit for inductive load switching") | - | 55 | - | μ J |
| $E_{off(2)}$ | Turn-off switching energy | | - | 85 | - | μ J |
| E_{ts} | Total switching energy | | - | 140 | - | μ J |
| $E_{on(1)}$ | Turn-on switching energy | $V_{CC} = 390\text{ V}$, $I_C = 5\text{ A}$, $R_G = 10\ \Omega$, $V_{GE} = 15\text{ V}$, $T_j = 125^\circ\text{C}$ (see Figure 18 : "Test circuit for inductive load switching") | - | 87 | - | μ J |
| $E_{off(2)}$ | Turn-off switching energy | | - | 162 | - | μ J |
| E_{ts} | Total switching energy | | - | 249 | - | μ J |

Notes:

(1)Including the reverse recovery of the diode.

(2)Including the tail of the collector current.

Table 8: Collector-emitter diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|------------------|--------------------------|---|------|------|------|------|
| V _F | Forward on-voltage | I _F =5 A | - | 2 | - | V |
| | | I _F =5 A, T _j =125 °C | - | 1.6 | - | V |
| t _{rr} | Reverse recovery time | I _F =5 A, V _R =40 V, di/dt=100 A/μs (see Figure 21: "Diode reverse recovery waveform") | - | 22 | - | ns |
| Q _{rr} | Reverse recovery charge | | - | 14 | - | nC |
| I _{rrm} | Reverse recovery current | | - | 1.3 | - | A |
| t _{rr} | Reverse recovery time | I _F =5 A, V _R =40 V, T _j =125 °C, di/dt=100 A/μs (see Figure 21: "Diode reverse recovery waveform") | - | 35 | - | ns |
| Q _{rr} | Reverse recovery charge | | - | 40 | - | nC |
| I _{rrm} | Reverse recovery current | | - | 2.2 | - | A |

2.1 Electrical characteristics (curves)

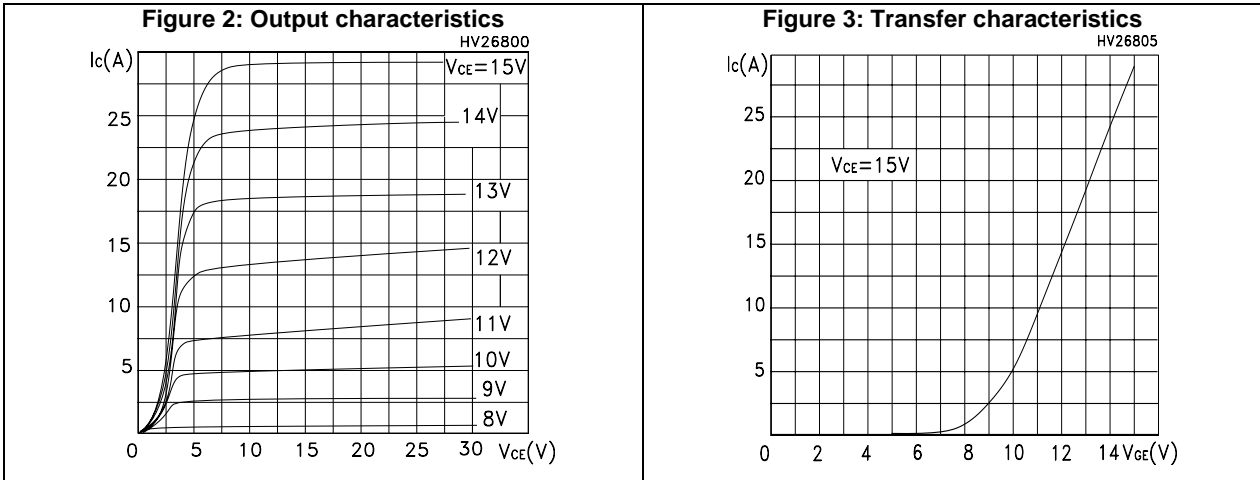


Figure 8: Normalized gate threshold voltage vs temperature

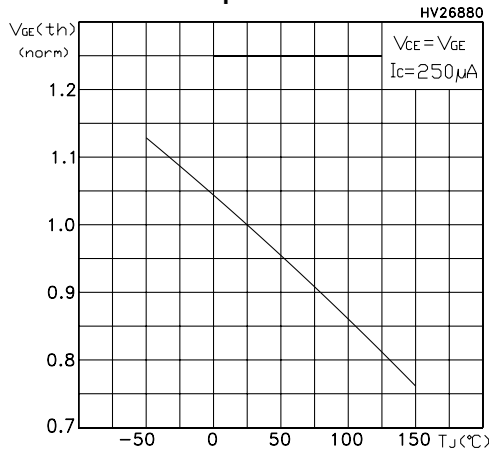


Figure 9: Collector-emitter on voltage vs collector current

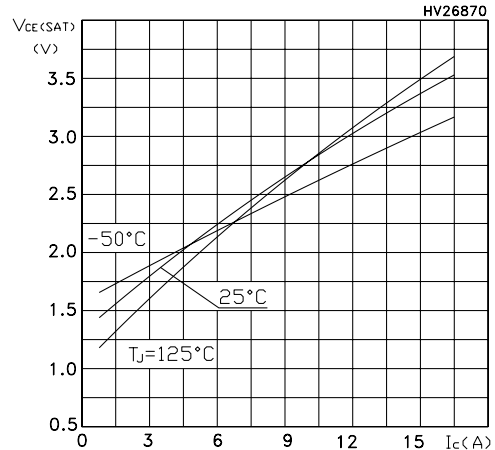


Figure 10: Normalized breakdown voltage vs temperature

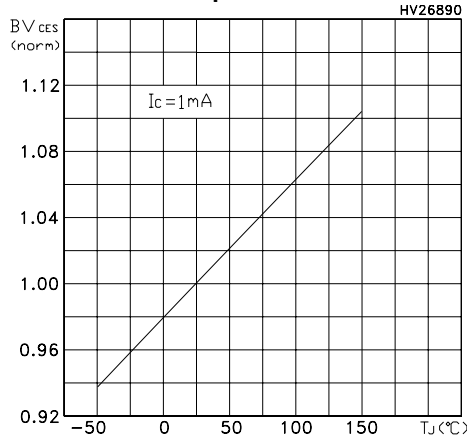


Figure 11: Switching energy vs temperature

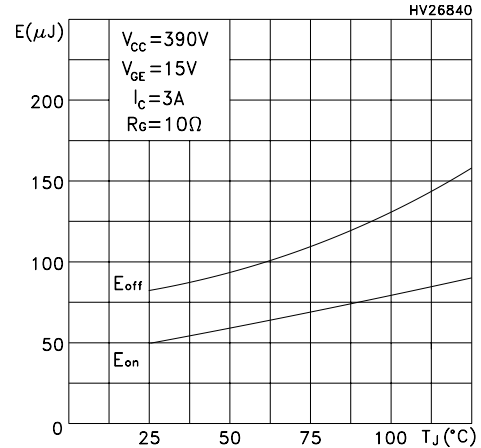


Figure 12: Switching energy vs gate resistance

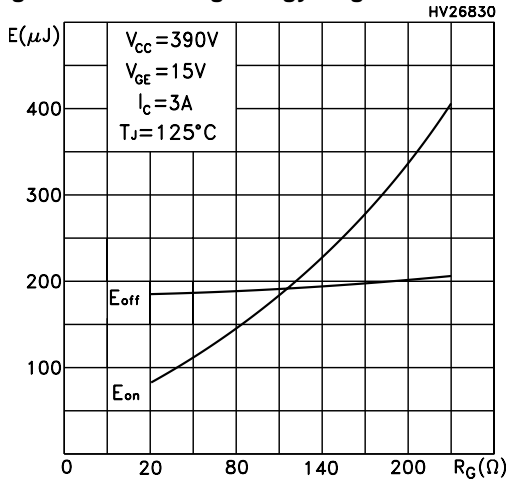


Figure 13: Switching energy vs collector current

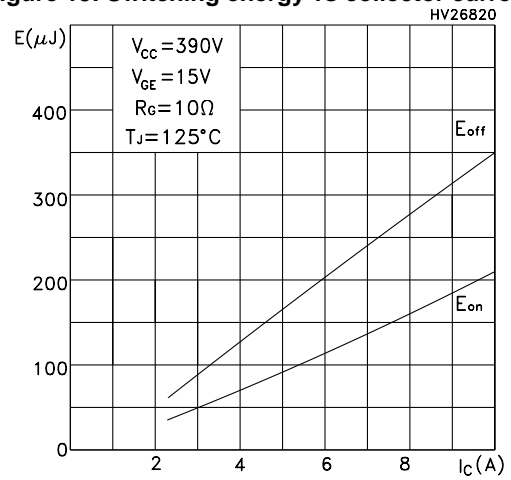


Figure 14: Thermal impedance for D²PAK, DPAK and TO-220

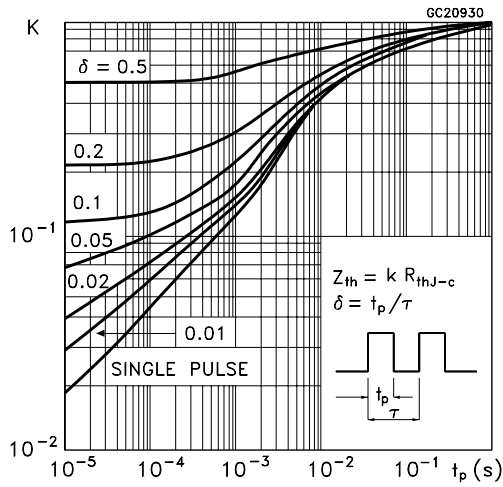


Figure 15: Turn-off SOA

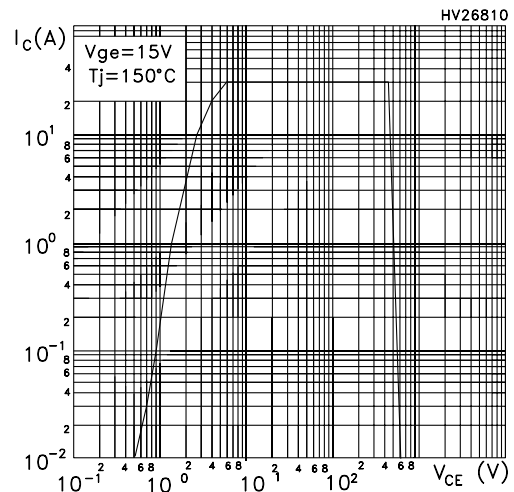


Figure 16: Emitter-collector diode characteristics

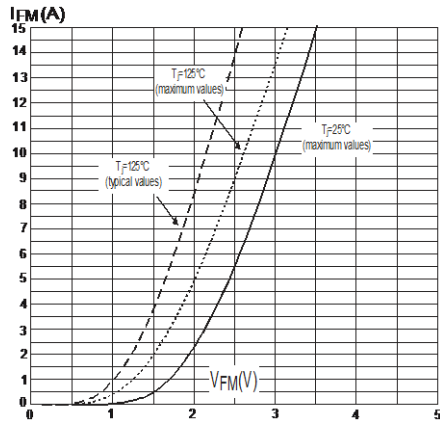
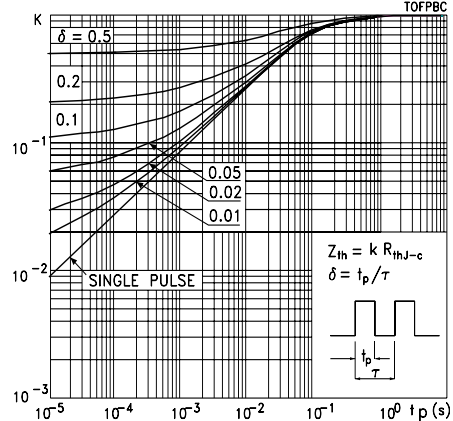


Figure 17: Thermal impedance for TO-220FP



4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

4.1 D²PAK (TO-263) type A package information

Figure 22: D²PAK (TO-263) type A package outline



Table 9: D²PAK (TO-263) type A package mechanical data

| Dim. | mm | | |
|------|-------|------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| A1 | 0.03 | | 0.23 |
| b | 0.70 | | 0.93 |
| b2 | 1.14 | | 1.70 |
| c | 0.45 | | 0.60 |
| c2 | 1.23 | | 1.36 |
| D | 8.95 | | 9.35 |
| D1 | 7.50 | 7.75 | 8.00 |
| D2 | 1.10 | 1.30 | 1.50 |
| E | 10.00 | | 10.40 |
| E1 | 8.50 | 8.70 | 8.90 |
| E2 | 6.85 | 7.05 | 7.25 |
| e | | 2.54 | |
| e1 | 4.88 | | 5.28 |
| H | 15.00 | | 15.85 |
| J1 | 2.49 | | 2.69 |
| L | 2.29 | | 2.79 |
| L1 | 1.27 | | 1.40 |
| L2 | 1.30 | | 1.75 |
| R | | 0.40 | |
| V2 | 0° | | 8° |

Figure 23: D²PAK (TO-263) type A recommended footprint (dimensions are in mm)



Footprint

4.2 D²PAK (TO-263) type B package information

Figure 24: D²PAK (TO-263) type B package outline



Table 10: D²PAK (TO-263) type B mechanical data

| Dim. | mm | | |
|------|----------|------|-------|
| | Min. | Typ. | Max. |
| A | 4.36 | | 4.56 |
| A1 | 0 | | 0.25 |
| b | 0.70 | | 0.90 |
| b1 | 0.51 | | 0.89 |
| b2 | 1.17 | | 1.37 |
| b3 | 1.36 | | 1.46 |
| c | 0.38 | | 0.694 |
| c1 | 0.38 | | 0.534 |
| c2 | 1.19 | | 1.34 |
| D | 8.60 | | 9.00 |
| D1 | 6.90 | | 7.50 |
| E | 10.15 | | 10.55 |
| E1 | 8.10 | | 8.70 |
| e | 2.54 BSC | | |
| H | 15.00 | | 15.60 |
| L | 1.90 | | 2.50 |
| L1 | | | 1.65 |
| L2 | | | 1.78 |
| L3 | | 0.25 | |
| L4 | 4.78 | | 5.28 |

Figure 25: D²PAK (TO-263) type B recommended footprint (dimensions are in mm)



4.3 DPAK (TO-252) type A package information

Figure 26: DPAK (TO-252) type A package outline

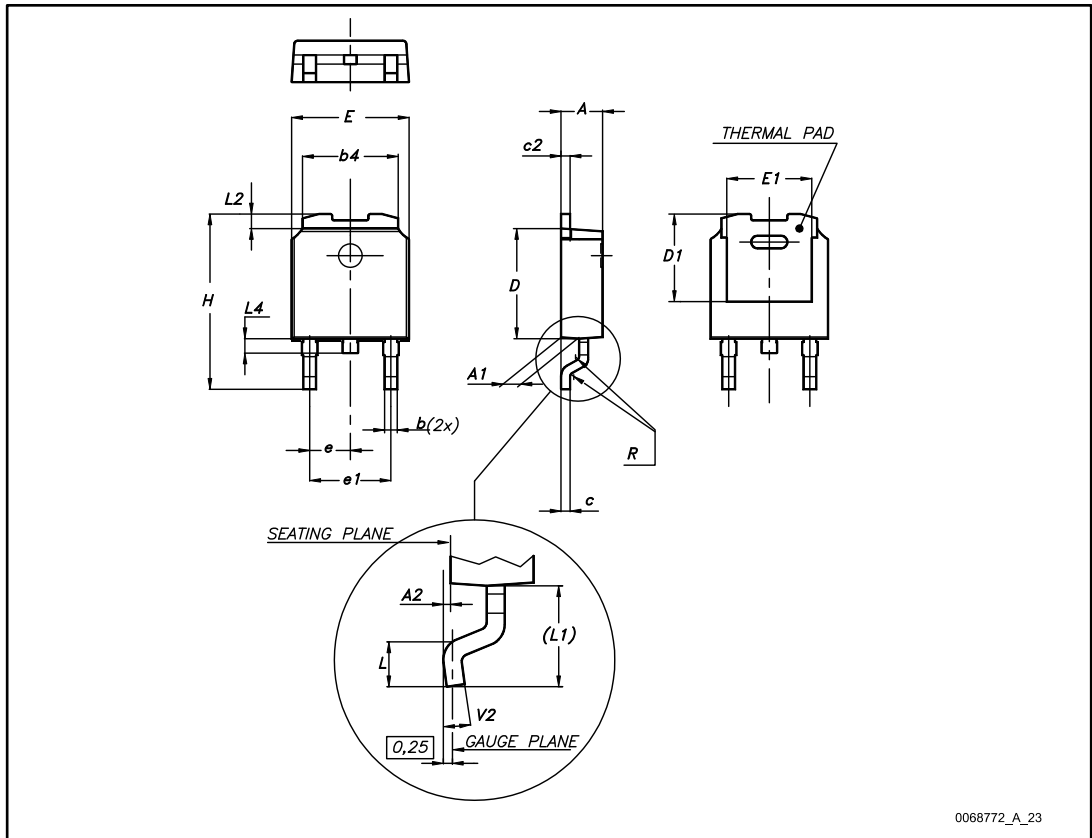
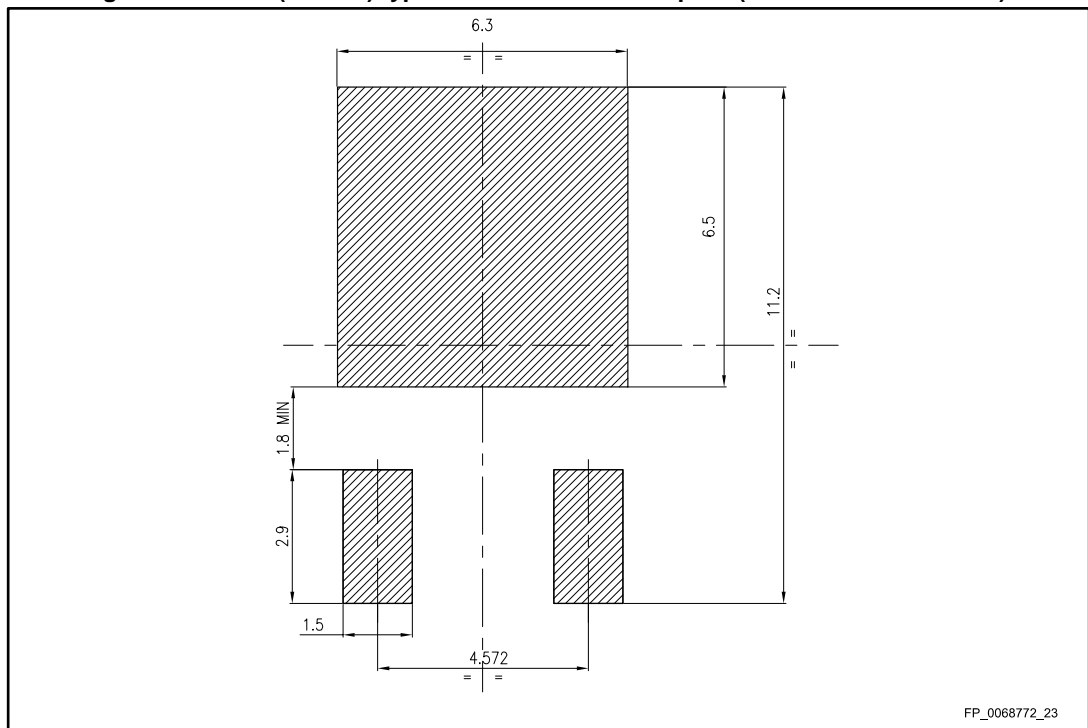


Table 11: DPAK (TO-252) type A mechanical data

| Dim. | mm | | |
|------|------|------|-------|
| | Min. | Typ. | Max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | 4.95 | 5.10 | 5.25 |
| E | 6.40 | | 6.60 |
| E1 | 4.60 | 4.70 | 4.80 |
| e | 2.16 | 2.28 | 2.40 |
| e1 | 4.40 | | 4.60 |
| H | 9.35 | | 10.10 |
| L | 1.00 | | 1.50 |
| (L1) | 2.60 | 2.80 | 3.00 |
| L2 | 0.65 | 0.80 | 0.95 |
| L4 | 0.60 | | 1.00 |
| R | | 0.20 | |
| V2 | 0° | | 8° |

Figure 27: DPAK (TO-252) type A recommended footprint (dimensions are in mm)



4.4 TO-220FP package information

Figure 28: TO-220FP package outline



7012510_Rev_12_B

Table 12: TO-220FP package mechanical data

| Dim. | mm | | |
|------|------|------|------|
| | Min. | Typ. | Max. |
| A | 4.4 | | 4.6 |
| B | 2.5 | | 2.7 |
| D | 2.5 | | 2.75 |
| E | 0.45 | | 0.7 |
| F | 0.75 | | 1 |
| F1 | 1.15 | | 1.70 |
| F2 | 1.15 | | 1.70 |
| G | 4.95 | | 5.2 |
| G1 | 2.4 | | 2.7 |
| H | 10 | | 10.4 |
| L2 | | 16 | |
| L3 | 28.6 | | 30.6 |
| L4 | 9.8 | | 10.6 |
| L5 | 2.9 | | 3.6 |
| L6 | 15.9 | | 16.4 |
| L7 | 9 | | 9.3 |
| Dia | 3 | | 3.2 |

4.5 TO-220 type A package information

Figure 29: TO-220 type A package outline



Table 13: TO-220 type A package mechanical data

| Dim. | mm | | |
|------|-------|-------|-------|
| | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 |
| b | 0.61 | | 0.88 |
| b1 | 1.14 | | 1.55 |
| c | 0.48 | | 0.70 |
| D | 15.25 | | 15.75 |
| D1 | | 1.27 | |
| E | 10.00 | | 10.40 |
| e | 2.40 | | 2.70 |
| e1 | 4.95 | | 5.15 |
| F | 1.23 | | 1.32 |
| H1 | 6.20 | | 6.60 |
| J1 | 2.40 | | 2.72 |
| L | 13.00 | | 14.00 |
| L1 | 3.50 | | 3.93 |
| L20 | | 16.40 | |
| L30 | | 28.90 | |
| øP | 3.75 | | 3.85 |
| Q | 2.65 | | 2.95 |

4.6 D²PAK (TO-263) type A packing information

Figure 30: D²PAK type A tape outline

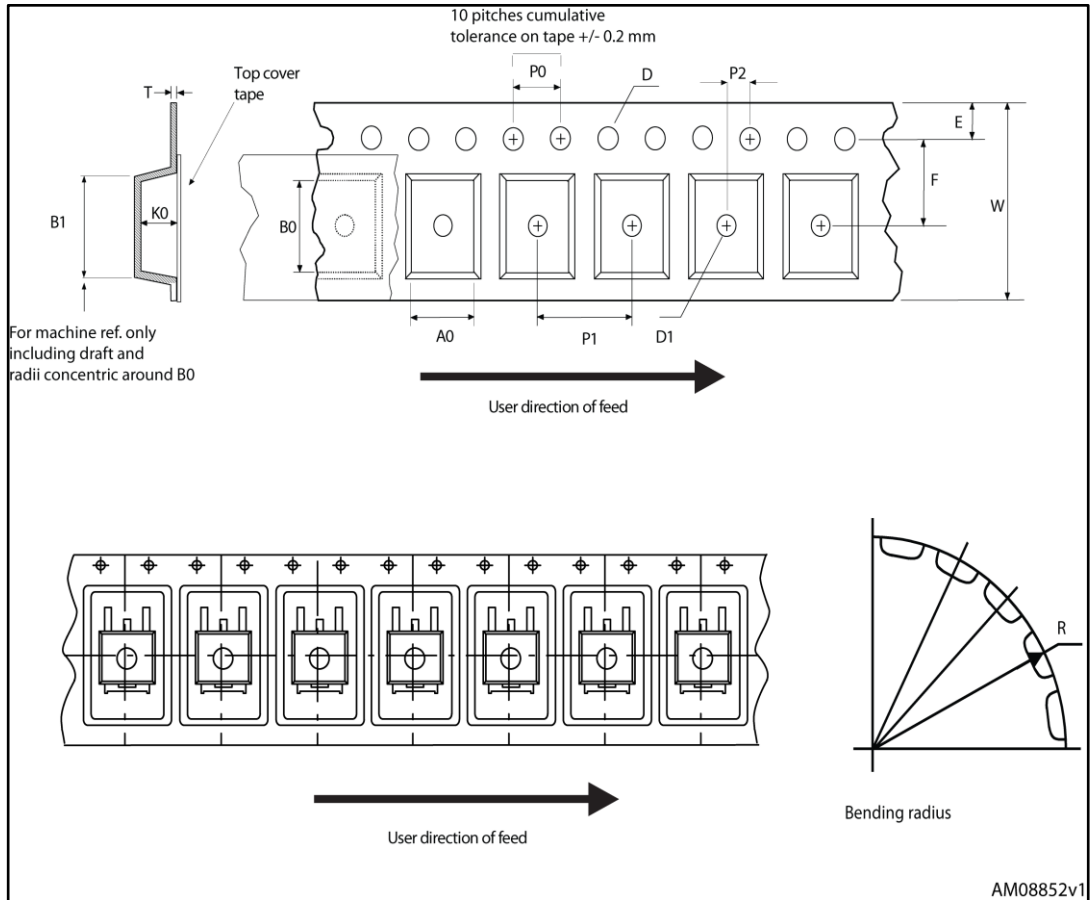


Figure 31: D²PAK type A reel outline

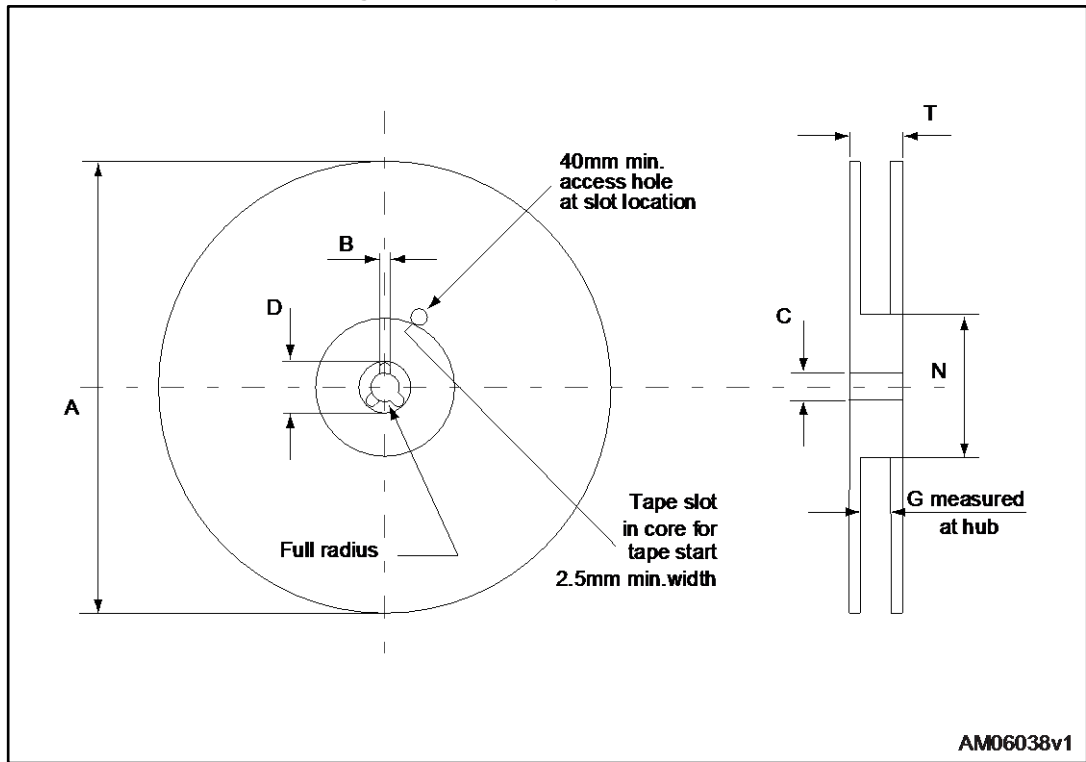


Table 14: D²PAK type A tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|---------------|------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 10.5 | 10.7 | A | | 330 |
| B0 | 15.7 | 15.9 | B | 1.5 | |
| D | 1.5 | 1.6 | C | 12.8 | 13.2 |
| D1 | 1.59 | 1.61 | D | 20.2 | |
| E | 1.65 | 1.85 | G | 24.4 | 26.4 |
| F | 11.4 | 11.6 | N | 100 | |
| K0 | 4.8 | 5.0 | T | | 30.4 |
| P0 | 3.9 | 4.1 | | | |
| P1 | 11.9 | 12.1 | Base quantity | | 1000 |
| P2 | 1.9 | 2.1 | Bulk quantity | | 1000 |
| R | 50 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 23.7 | 24.3 | | | |

4.7 D²PAK (TO-263) type B packing information

Figure 32: D2PAK type B tape outline

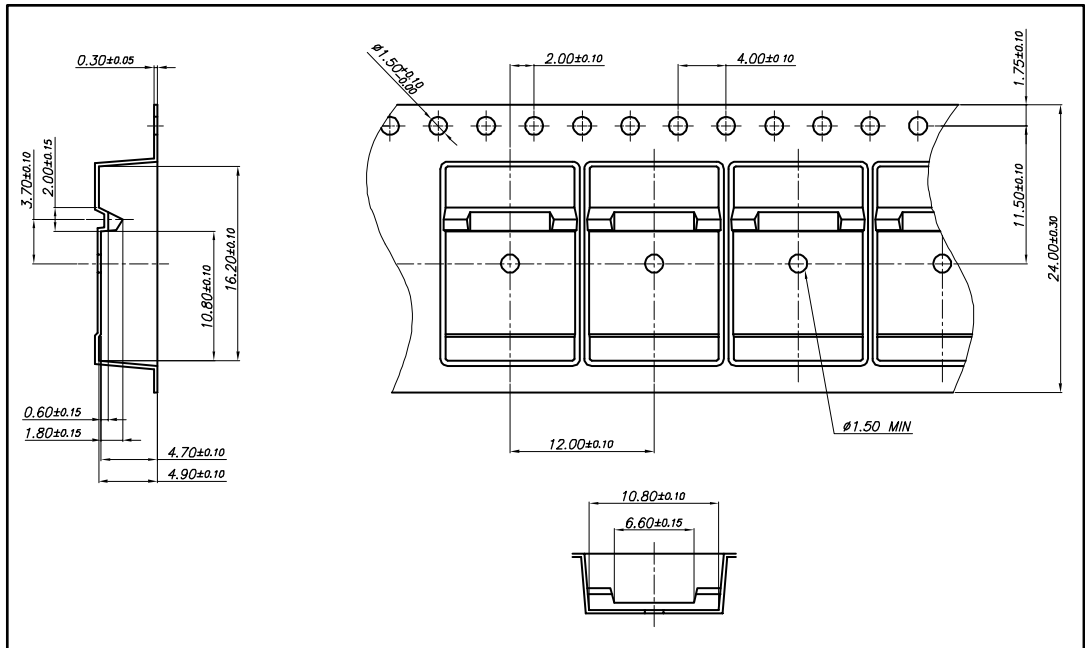
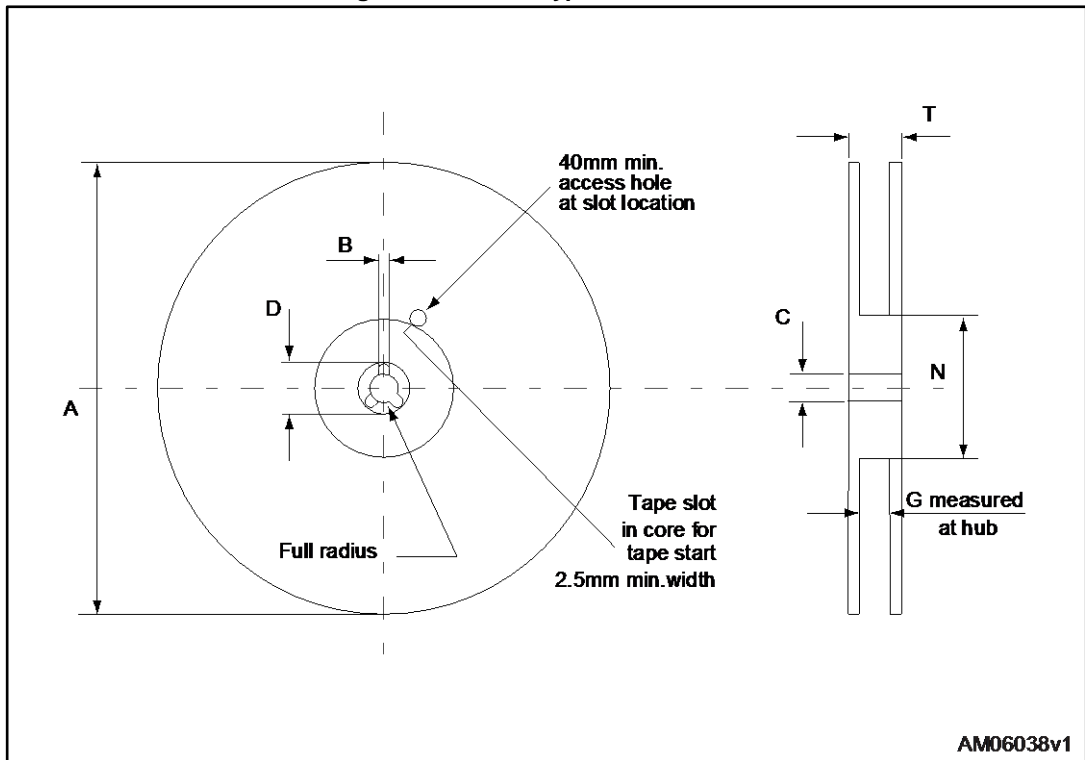


Figure 33: D2PAK type B reel outline



AM06038v1

Table 15: D²PAK type B reel mechanical data

| Dim. | mm | |
|------|------|------|
| | Min. | Max. |
| A | | 330 |
| B | 1.5 | |
| C | 12.8 | 13.2 |
| D | 20.2 | |
| G | 24.4 | 26.4 |
| N | 100 | |
| T | | 30.4 |

4.8 DPAK (TO-252) type A tape packing information

Figure 34: DPAK (TO-252) tape outline



Figure 35: DPAK (TO-252) reel outline

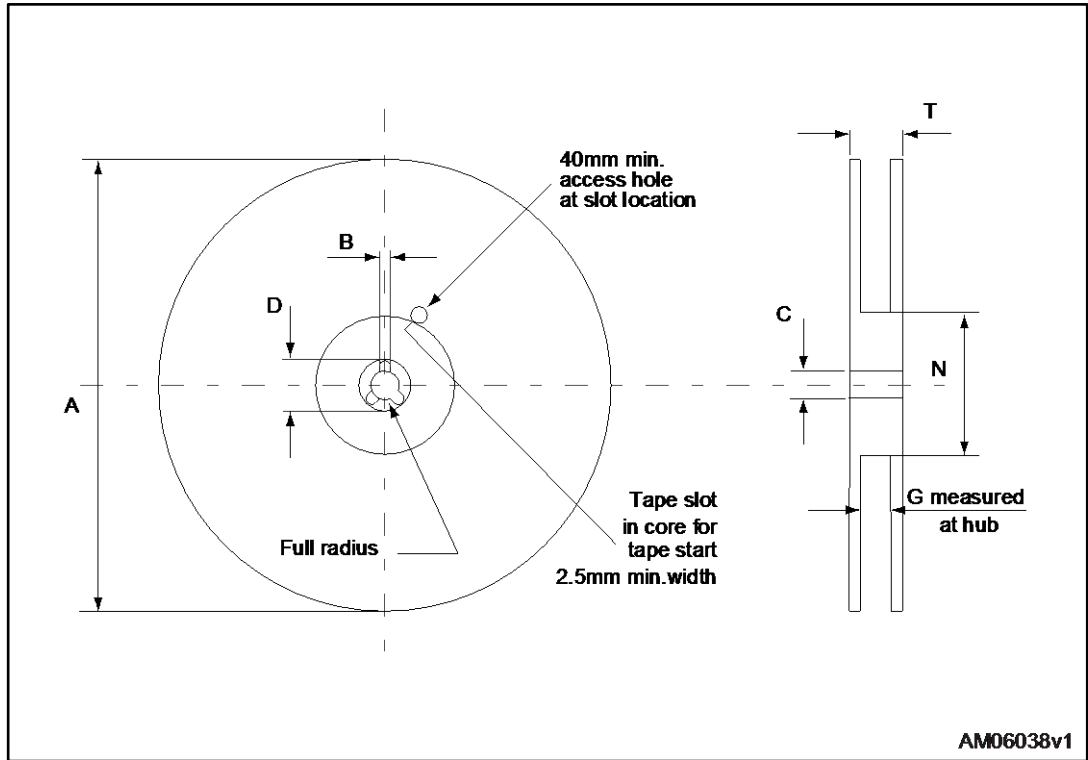


Table 16: DPAK (TO-252) tape and reel mechanical data

| Tape | | | Reel | | |
|------|------|------|-----------|------|------|
| Dim. | mm | | Dim. | mm | |
| | Min. | Max. | | Min. | Max. |
| A0 | 6.8 | 7 | A | | 330 |
| B0 | 10.4 | 10.6 | B | 1.5 | |
| B1 | | 12.1 | C | 12.8 | 13.2 |
| D | 1.5 | 1.6 | D | 20.2 | |
| D1 | 1.5 | | G | 16.4 | 18.4 |
| E | 1.65 | 1.85 | N | 50 | |
| F | 7.4 | 7.6 | T | | 22.4 |
| K0 | 2.55 | 2.75 | | | |
| P0 | 3.9 | 4.1 | Base qty. | | 2500 |
| P1 | 7.9 | 8.1 | Bulk qty. | | 2500 |
| P2 | 1.9 | 2.1 | | | |
| R | 40 | | | | |
| T | 0.25 | 0.35 | | | |
| W | 15.7 | 16.3 | | | |

5 Revision history

Table 17: Document revision history

| Date | Revision | Changes |
|-------------|----------|---|
| 14-Jun-2005 | 1 | First release. |
| 19-Jul-2005 | 2 | Complete version. |
| 27-Jan-2006 | 3 | Inserted ecopack indication. |
| 01-Mar-2006 | 4 | The document has been reformatted. |
| 08-Feb-2007 | 5 | Modified value on <i>Table 6.: Switching on/off (inductive load)</i> . |
| 24-Nov-2009 | 6 | Inserted DPAK package option. |
| 06-Jun-2017 | 7 | Modified part numbers on cover page. Updated Section 4: "Package information" . Minor text changes. |

IMPORTANT NOTICE – PLEASE READ CAREFULLY

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- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



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